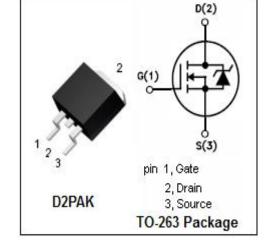


Isc N-Channel MOSFET Transistor

SPB16N50C3

• FEATURES

- With TO-263(D2 PAK) packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

- Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	V		
V_{GS}	Gate-Source Voltage	±20	V	
I _D	Drain Current-Continuous	А		
P _D	Total Dissipation @T _C =25°C 160		W	
Tj	Max. Operating Junction Temperature	-55~150	$^{\circ}$	
T _{stg}	Storage Temperature -55~150		°C	

В S D Q C U mm MIN MAX 10 A В 6.6 6.8 15.23 15.25 10.15 10.17 0.76 0.78 G 1.26 1.6 1.4 1.33 1.35 0.4 0.6 4.8 4.6 8.69 8.71 5.28 5.30 1.28 1.26 0.0 0.37 0.39 2.80

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.78	°C/W

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT			
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 250uA	500			V			
V _{GS(th)}	Gate Threshold Voltage	$V_{DS}=V_{GS}$; $I_D=675uA$	2.1	3	3.9	V			
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 10A		250	280	mΩ			
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±100	nA			
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 500V; V _{GS} = 0V		0.1	1	μА			
V _{SD}	Diode forward voltage	I _S = 16A, V _{GS} = 0V		1	1.2	V			



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